



Product Overview

NTMFS6B14N: Power MOSFET 100V 50A 14m Single N-Channel SO-8FL

For complete documentation, see the data sheet

Product Description

Power MOSFET 100V 50A 14m Single N-Channel SO-8FL

Features	Benefits
<ul style="list-style-type: none">Low RDS(on)Low input capacitance	<ul style="list-style-type: none">Minimize conduction lossesMinimize switching losses
Applications	End Products
<ul style="list-style-type: none">Point of load modules	<ul style="list-style-type: none">Netcom, TelecomServers

Part Electrical Specifications

Product	Compliance	Status	Channel Polarity	Configuration	V _{DS(BR)} Min (V)	V _{GS} Max (V)	V _{GS} (th) Max (V)	I _D Max (A)	P _D Max (W)	r _{DS(on)} Max @ V _{GS} = 2.5 V (m)	r _{DS(on)} Max @ V _{GS} = 4.5 V (m)	r _{DS(on)} Max @ V _{GS} = 10 V (m)	Q _g Typ @ V _{GS} = 4.5 V (nC)	Q _g Typ @ V _{GS} = 10 V (nC)	Q _{gd} Typ @ V _{GS} = 4.5 V (nC)	Q _{tr} Typ (nC)	C _{iss} Typ (pF)	C _{oss} Typ (pF)	C _{rss} Typ (pF)	Packaging Type
NTMFS6B14NT1G	Pb-free Halide free	Active	N-Channel	Single	100	±20	4	50	77			15		20		50	1300	260	18	SO-8FL / DF N-5
NTMFS6B14NT3G	Pb-free Halide free	Active	N-Channel	Single	100	±20	4	50	77			15		20		50	1300	260	18	SO-8FL / DF N-5

For more information please contact your local sales support at www.onsemi.com

Created on: 7/11/2015